

DESCRIPTION

SiC Schottky Diode has no switching loss, provides improved system efficiency against Si diodes by utilizing new semiconductor material—Silicon Carbide, enables higher operating frequency, and helps increasing power density and reduction of system size /cost. Its high reliability ensures robust operation during surge or over_voltage conditions.

FEATURES

- Max Junction Temperature 175° C
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery

MECHANICAL DATA

- Case: JEDEC TO-247AB
- Molding compound meets UL94V-0 flammability rating
- Terminals: Lead solderable per J-STD-002 and JESD22-B102
- Polarity: As marked
- Mounting Torque: 10 in-lbs maximum

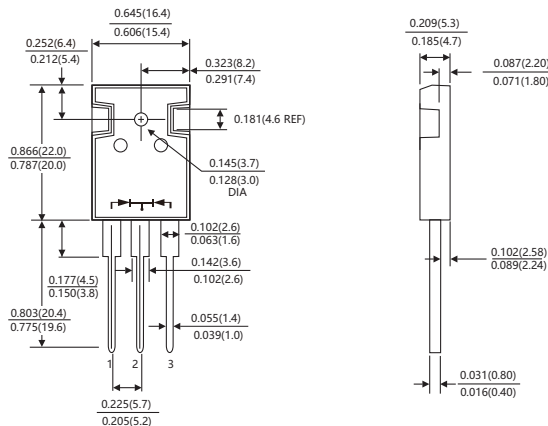
TYPICAL APPLICATIONS

- General Purpose
- SMPS, Solar inverter, UPS
- Power Switching Circuits

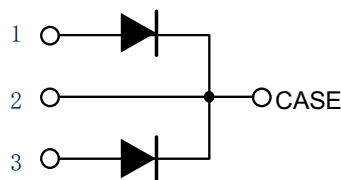
KEY PERFORMANCE AND PACKAGE PARAMETERS (leg/device)

Type	V _{DC}	I _F	Q _c	T _{j,max}	Package
SC2065PT	650V	10A/20A	25nC/50nC	175°C	TO-247AB

TO-247AB



Dimensions in inches and (millimeters)



RATINGS AND CHARACTERISTIC OF SC2065PT

MAXIMUM RATINGS

(Ratings at 25°C ambient temperature unless otherwise specified)

Parameter	Symbol	Value (leg/device)	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	650	V
Continuous Forward Current for $R_{th(j-c)}$	I_F	10/20 ($T_c \leq 140^\circ\text{C}$)	A
Non-Repetitive Forward Surge Current (Half-Sine Pulse, $t_p=8.3\text{ms}$)	$I_{F,SM}$	75/150 ($T_c=25^\circ\text{C}$) 60/120 ($T_c=150^\circ\text{C}$)	A
I^2t value	$\int i^2t$	23/92 ($T_c=25^\circ\text{C}$) 15/60 ($T_c=150^\circ\text{C}$)	A^2S
Diode dv/dt ruggedness ($V_R=0\dots 960\text{V}$)	dv/dt	80	V/nS
Power dissipation for $R_{th(j-c,max)}$ ($T_c=25^\circ\text{C}$)	P_{tot}	150/180	W
Operating junction temperature range	T_j	-55...175	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55...175	$^\circ\text{C}$

THERMAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ Unless otherwise noted)

Parameter	Symbol	Value (leg/device)		Unit
		Typ	Max	
Diode thermal resistance junction-case	$R_{th(j-c)}$	0.8/0.6	1.0/0.8	K/W

RATINGS AND CHARACTERISTIC OF SC2065PT

ELECTRICAL CHARACTERISTICS (T_A=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Value(leg/device)			Unit
			min	typ	max	
DC blocking voltage	V _{DC}	T _j =25...175°C	650			V
Diode forward voltage	V _F	IF=10A T _j =25°C IF=10A T _j =125°C IF=10A T _j =175°C per diode; Fig. 3		1.35 1.50 1.55	1.45 1.60 1.65	V
Reverse current	I _R	VR=650V T _j =25°C VR=650V T _j =125°C VR=650V T _j =175°C per diode; Fig. 4			50 100 200	uA

DYNAMIC CHARACTERISTICS(at T_j=25°C, unless otherwise specified)

Parameter	Symbol	conditions	Value(leg/device)			Unit
			min	typ	max	
Total capacitive charge	Q _c	VR=1200V,IF=10A di/dt=200A/uS T _j =25°C		25/50		nC
Total capacitance	C	V _R =0V,f=1MHz V _R =200V,f=1MHz V _R =400V,f=1MHz T _j =25°C		440/880 57/114 46/92		pF

RATINGS AND CHARACTERISTIC OF SC2065PT

FIG.1-FORWARD CURRENT DERATING CURVE(device)

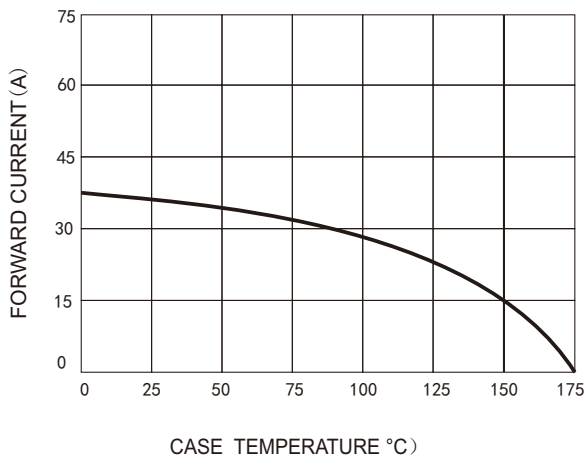


FIG.2-TYPICAL JUNCTION CAPACITANCE(per leg)

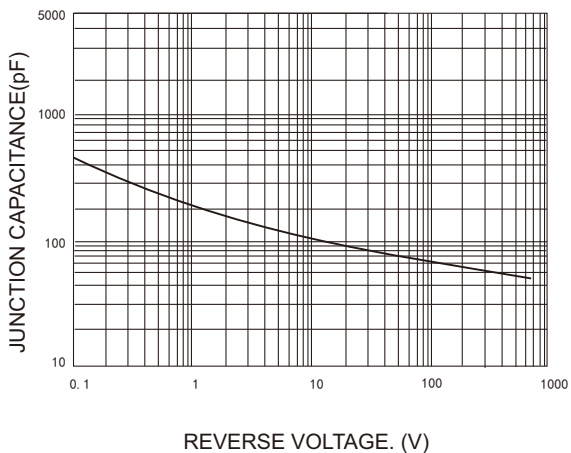


FIG.3-FORWARD CURRENT DERATING CURVE(per leg)

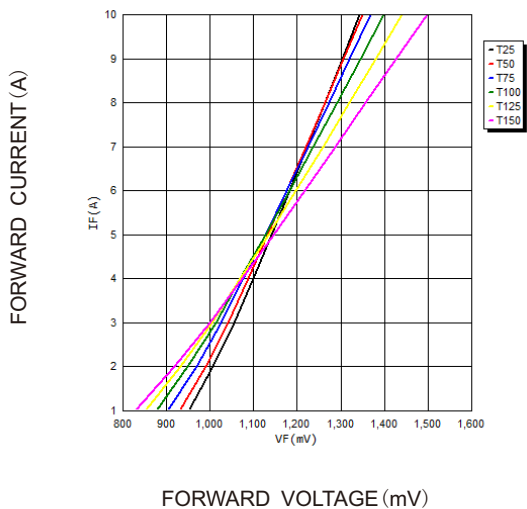
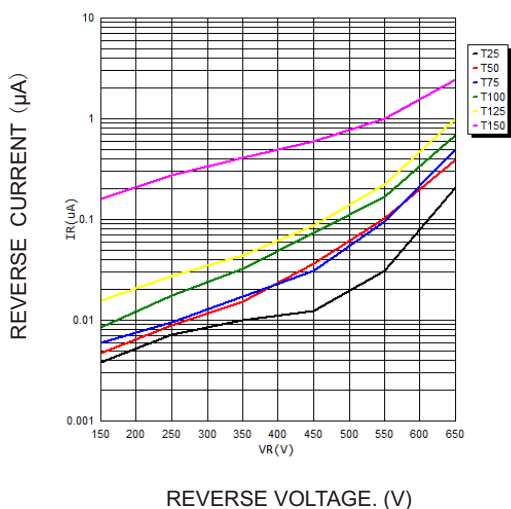


FIG.4-REVERSE CHARACTERISTICS(per leg)



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